TOSHIBA Photocoupler GaAs Ired & Photo-Triac

TLP3521

Triac Driver
Programmable Controllers
AC-Output Module
Solid State Relay

The TOSHIBA TLP3521 consists of a zero voltage crossing turn—on photo—triac optically coupled to a gallium arsenide infrared emitting diode in a 16 lead plastic DIP package.

• Peak off-state voltage: 400V (min.)

• Trigger LED current: 10mA (max.)

• On-state current: 1.0A_{rms} (max.)

• Isolation voltage: 2500V_{rms} (min.)

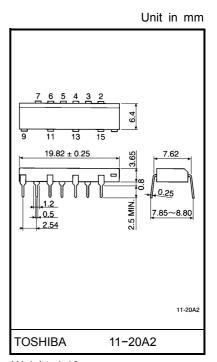
• UL recognized: UL1577, file no. E67349

• Trigger LED current

Classi- fication *	Trigger LED Current (mA) $V_T = 6 \text{ V, Ta} = 25^{\circ}\text{C}$ Min. Max.		Marking Of Classification
(IFT5)	_	5.0	T5
(IFT7)	_	7.0	T5, T7
Standard	_	10	T5, T7, blank

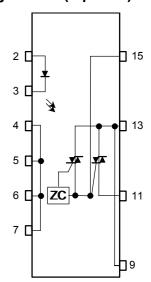
*Ex. (IFT5); TLP3521 (IFT5)

(Note) Application type name for certification test, please use standard product type name, i.e. TLP3521 (IFT5): TLP3521



Weight: 1.13g

Pin Configuration (top view)



2 : Anode 3 : Cathode 4,5,6,7 : N.C. 9,13 : Triac T2 11 : Triac T1 15 : Triac gate

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Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit
	Forward current	l _F	50	mA	
	Forward current derating (Ta ≥ 53°C)		ΔI _F / °C	-0.7	mA / °C
LED	Peak forward current (100µs pulse	e, 100pps)	I _{FP}	1	А
	Reverse voltage		V _R	5	V
	Junction temperature		Tj	125	°C
	Off-state output terminal voltage		V_{DRM}	400	V
	On-state RMS current	Ta = 40°C	l= (0.40)	1.0	Α
_		Ta = 60°C	I _T (RMS)	0.7	
Detector	On-state current derating (Ta ≥ 40	ΔI _T / °C	-14.3	mA / °C	
Det	Peak current from snubber circuit (100µs pulse, 120pps)	I _{SP}	2	А	
	Peak nonrepetitive surge current (I _{TSM}	10	А	
	Junction temperature	Tj	110	°C	
Storage temperature range			T _{stg}	-40~125	°C
Operating temperature range			T _{opr}	-20~80	°C
Lead soldering temperature (10s)			T _{sol}	260	°C
Isolation voltage (AC, 1 min., R.H.≤ 60%) (Note)			BVS	2500	V _{rms}

(Note) Device considered a two terminal: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V_{AC}	_	_	120	V _{ac}
Forward current	I _F	15	20	25	mA
Peak current from snubber circuit	I _{SP}	_	_	1	Α
Operating temperature	T _{opr}	-20	_	80	°C

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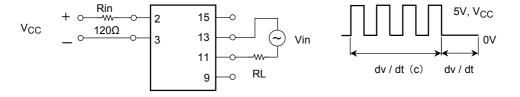
Individual Electrical Characteristics (Ta = 25°C)

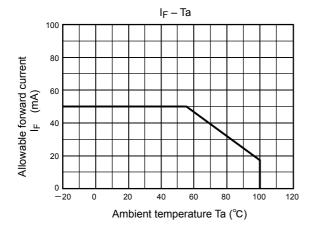
Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
LED	Forward voltage	V _F	I _F = 10mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5V	_	_	10	μA
	Capacitance	C _T	V = 0, f = 1MHz	_	30	_	pF
Detector	Peak off-state current	I _{DRM}	V _{DRM} =400 V, Ta = 110°C	_	_	100	μA
	Peak on-state voltage	V _{TM}	I _{TM} = 1.5A	_	_	3.0	V
	Holding current	lΗ	R _L = 100Ω	_	_	25	mA
	Critical rate of rise of off–state voltage	dv / dt	$V_{in} = 120V_{rms}$ (Fig.1)	200	500	_	V / µs
	Critical rate of rise of commutating voltage	dv / dt (c)	$V_{in} = 120V_{rms}, I_T = 1.0A_{rms}$ (Fig.1)	_	5	_	V / µs

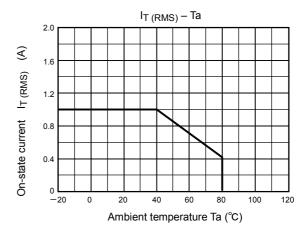
Coupled Electrical Characteristics (Ta = 25°C)

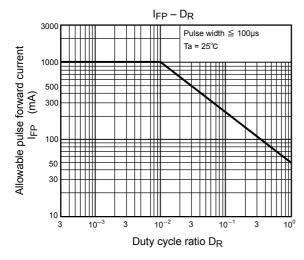
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	V _T = 6V	_	_	10	mA
Inhibit voltage	V _{IH}	I _F = rated I _{FT}	_	_	50	V
Leakage in inhibited state	I _{IH}	I _F = rated I _{FT} V _T = rated V _{DRM}	-	200	1	μΑ
Capacitance (input to output)	C _S	V _S = 0, f = 1MHz	-	1.5	١	pF
Isolation resistance	R _S	V _S = 500V	5×10 ¹⁰	10 ¹⁴	_	Ω
	BVS	AC, 1 minute	2500	_	_	V _{rms}
Isolation voltage		AC, 1 second, in oil	_	5000	_	
		DC, 1 minute, in oil	_	5000	_	V _{dc}

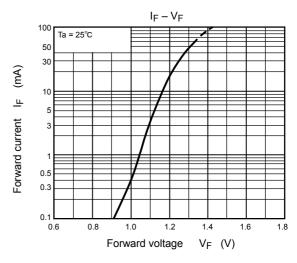
Fig.1: dv / dt test circuit

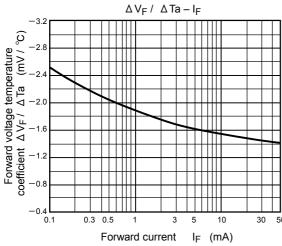


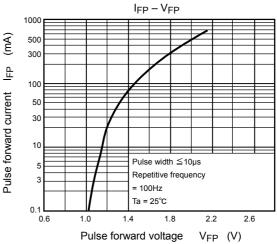


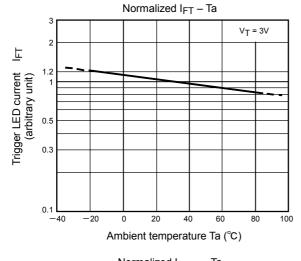


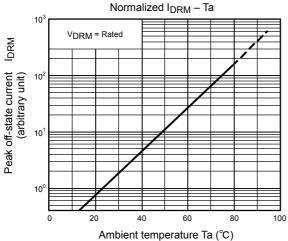


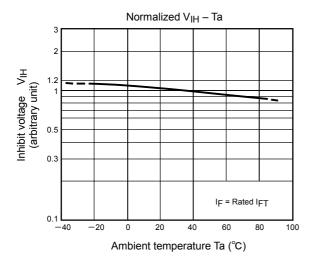


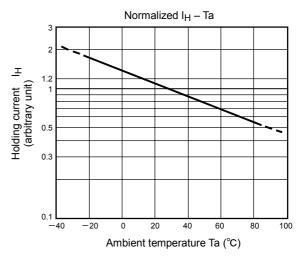


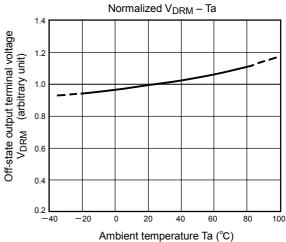


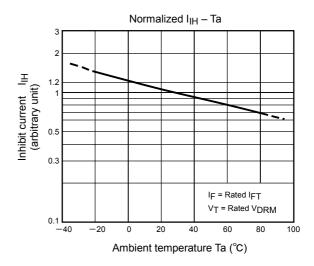












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